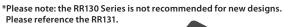


1 Description

The RedRock 130 Series is an integrated digital magnetic switch ideal for use in medical, industrial, automotive and consumer switching applications. It is based on patented Tunneling Magnetoresistance (TMR) technology with integrated CMOS process. The RR130 Series can operate in low magnetic fields with large air gaps. The open drain output can interface with a system voltage up to 3.9V for added design flexibility. The RR130 Series provides high sensitivity with low power consumption in a small footprint package.





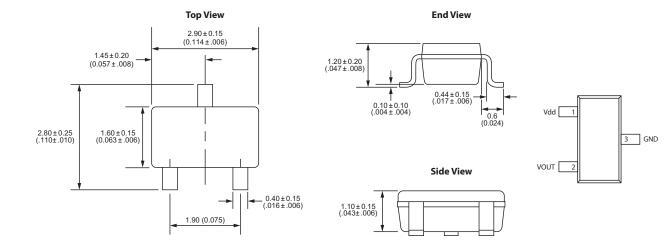
4 Dimensions Millimeters (Inches)

2 Features

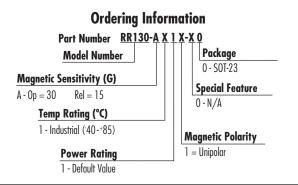
- High sensitivity
- Stable temperature performance
- Resistant to mechanical stress
- Low power consumption
- High frequency performance
- Open drain MOSFET for design flexibility
- ► REACH Compliant
- ▶ RoHS Compliant (Pb)

3 Applications

- ► Door or lid closure detection
- Smart phones, tablets and laptops
- Bare glass reed switch replacement
- Motor controllers
- Proximity detection
- Power switch or open-close detection
- Water, electric and gas meters
- Fluid level detection
- "Wake-Up" functionality



5 Device Nomenclature







6 Specifications

Parameters	Units	Min	Тур	Мах
OPERATING CHARACTERISTICS ¹				
Operate Sensitivity	G	20	30	40
Release Sensitivity	G	8	15	25
Hysteresis	G		15	
Operate Time	ms		30	
Release Time	ms		30	
Temperature Coefficient of Operate Sensitivity	G/ºC		-0.05	
ELECTRICAL CHARACTERISTICS ¹				
Supply Voltage ² (V _{dd})	V	2.7	3.0	3.6
Average Current Drain	nA		350	400
System Voltage ² (V _{sys})	V			V _{dd} + 0.3
System Current ² (I _{sys})	mA			15
ABSOLUTE ENVIRONMENTAL RATINGS				
Operating Temperature: Industrial	°C	-40		85
Storage Temperature	°C	-55		150
Soldering Temperature	٥C			260
Max. Exposed Magnetic Field	G			100
ESD Level (HBM)	V			4000

Notes:

1. All characteristics as measured at 25°C

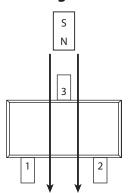
2. See "Application Circuit" for more information.

7 Application Circuit

Open Drain Output Application Circuit

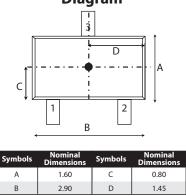
With the open drain output, the system voltage can range up to V_{dd} + 0.3V. Please keep in mind the supply voltage to the RR130 must not exceed 3.6V. A decoupling capacitor between the supply voltage and ground is required with placement close to the magnetic sensor. A typical capacitor value of 0.1 mF will suffice.

8 Sensor Polarity Diagram

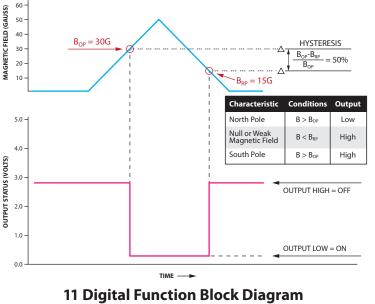


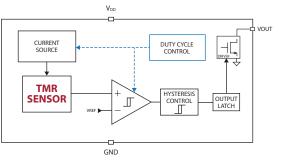
 $V_{dd} \qquad V_{SYS} \qquad R_{PULLUP}$ $\downarrow 0.1 \mu F \qquad RR130 \qquad V_{OUT}$ $\downarrow 0.1 \mu F \qquad V_{OUT}$

9 MTJ Sensor Location Diagram



10 Magnetic Field vs. Output Status



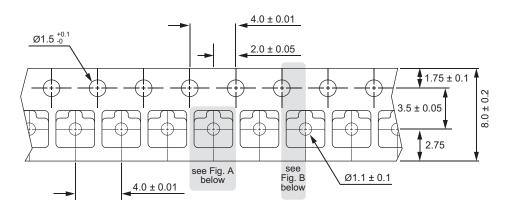


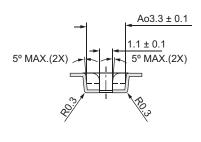




12 TMR Sensor & Switch Packaging

Standard packaging is Tape & Reel containing 3,000 pieces. Below is a chart of Tape & Reel dimensions for standard TMR products.





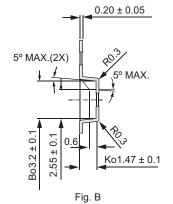
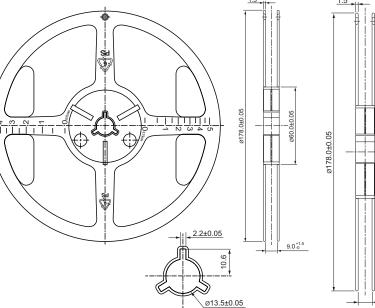
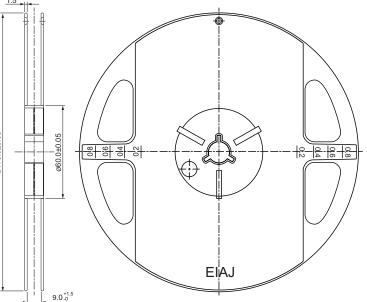


Fig. A

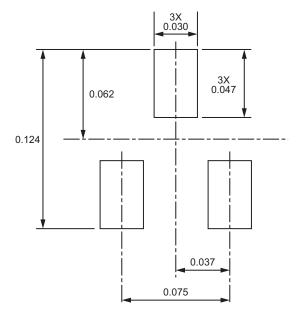




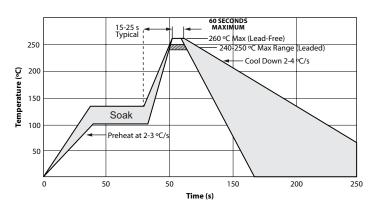




13 Suggested Solder Pad Layout



14 Suggested Reflow Profile



(Units in mm)

Notes:

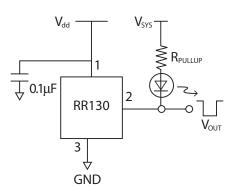
1. Fully compatible with standard no-lead solder profile, 260 °C for 1 minute max (3 cycles max)

2. Profile shown as example. Users are advised to develop their own board-level profile

3. Temperature tolerance: +0 °C, as measured at any point on the package or leads

4. MSL rating of 1 compatible with J-STD-020 or equivalent.

15 Application Circuits



RR130 Open Drain Output Application Circuit

With the open drain output, the system voltage can range up to V_{dd} + 0.3V. Please keep in mind the supply voltage to the RR130 must not exceed 3.6V. A decoupling capacitor between the supply voltage and ground is required with placement close to the magnetic sensor. A typical capacitor value of 0.1 μ F will suffice.





16 Glossary of Terms

Hysteresis: Hysteresis refers to the difference between two points of interest for a particular device. For digital sensors and switches, it represents the difference between the operate sensitivity and the release sensitivity, expressed either as an absolute value $(B_{OP} - B_{RP})$ or the % difference $(B_{OP} - B_{RP})/B_{OP}$. For an analog sensor, the hysteresis is the difference between the "magnet approach curve" and the "magnet recede curve."

Magnet Approach Curve: The magnet approach curve is the characteristic change in resistance of an analog TMR sensor as an applied magnetic field approaches the sensor, typically plotted as a function of the magnetic field strength.

Magnet Recede Curve: The magnet recede curve is the characteristic change in resistance of an analog TMR sensor as an applied magnetic field recedes from the sensor, typically plotted as a function of the magnetic field strength.

Magnetoresistance: Magnetoresistance is a phenomenon wherein the electrical resistance of certain materials changes when exposed to an externally-applied magnetic field.

Magnetic Transfer Curve: The magnetic transfer curve defines the characteristic behavior of an analog TMR sensor by combining both the magnet approach curve and the magnet receive curve together.

Magnetic Tunnel Junction: A magnetic tunnel junction is a thin film structure consisting of two magnetic layers separated by a thin insulator. Because the insulating layer is thin enough (typically a few nanometers), electrons can tunnel from one magnetic layer into the other.

Operate Sensitivity: The operate sensitivity defines the upper limit of the strength of an applied magnetic field that a digital TMR sensor or switch must operate.

Operate Time: The operate time is the difference, in time, between the application of a magnetic field and the output response of the device. In an analog sensor, the response is a change in output resistance. In a digital sensor, the response is a change in state of the electrical output.

Release Sensitivity: The release sensitivity defines the lower limit of the strength of an applied magnetic field that a digital TMR sensor or switch must release.

Release Time: The release time is the difference, in time, between the removal of an applied magnetic field and the output response of the device. In an analog sensor, the response is a change in output resistance. In a digital sensor, the response is a change in state of the electrical output.

Tunnel Magnetoresistance (TMR): Tunnel Magnetoresistance is the magnetoresistive effect that occurs in a magnetic tunnel junction.

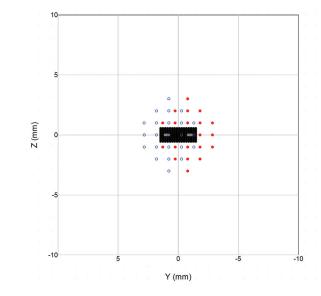




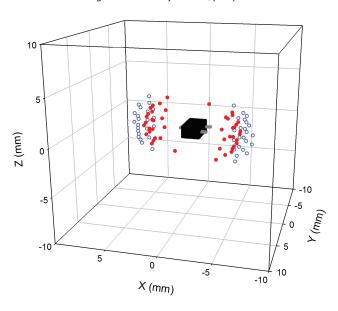
17 Magnetic Sensitivity Maps

Magnetic sensitivity maps show the operate and release loci in threedimensional space when a magnet is presented to a magnetically operated switch or sensor. The absolute operate and release distances between the magnet and the sensor will vary depending on the sensitivity of the switch and the strength of the magnet. However, the shape and direction of the operate loci stay relatively constant except for cases where the magnet is physically much larger than the sensor. These plots were generated using a 2mm^3 cubic shaped NdFeB N52 magnet with its North pole presented to the ground pin and a South pole presented to the opposite side.

RR130 Magnetic Sensitivity Pattern, YZ plane

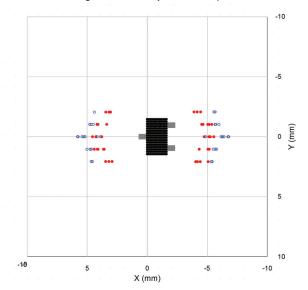


RR130 Magnetic Sensitivity Pattern, perspective view

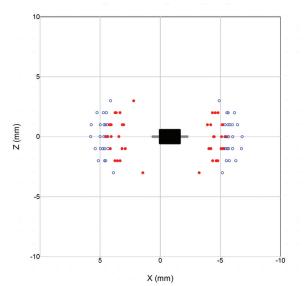


Operate Points
Release Points

RR130 Magnetic Sensitivity Pattern, XY plane



RR130 Magnetic Sensitivity Pattern, XZ plane





X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Board Mount Hall Effect/Magnetic Sensors category:

Click to view products by Coto manufacturer:

Other Similar products are found below :

HGPRDT005A AH277AZ4-AG1 AV-10379 AV-10448 SS41C AH1894-Z-7 ATS601LSGTN-LT-WU4-T TLE4917 50017859-003 TY-13101 TLE4976L AH49FNTR-G1 SS85CA AH277AZ4-BG1 TLE49614MXTSA1 AH3377-P-B AH211Z4-AG1 AH3360-FT4-7 SS460S-100SAMPLE 50065820-03 TLE4941PLUSCB AH374-P-A AH1806-P-A SS460P-T2 AH1913-W-7 SS413F TLE5046ICAKLRHALA1 TLE49421CHAMA2 TLE4941PLUSCXAMA1 AH1912-W-EVM AH1903-FA-EVM AH3774-W-EVM AH49FNTR-EVM MMC5633NJL AH3360-FA-EVM AH8502-FDC-EVM AH3366Q-SA-EVM AH3774-P-EVM KTH1601SU-ST3 MG910 MG910M MG911 MG610 MW921 TLE4998S3XALA1 TLE5011FUMA1 TLE5027CE6747HAMA1 TLE5109A16E2210XUMA1 TLI4966GHTSA1 TLI4906KHTSA1